Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

General Description

The MAX14430–MAX14432 are fast, low power, 4-channel, digital galvanic isolators using Maxim's proprietary process technology. These devices transfer digital signals between circuits with different power domains while using as little as 0.58mW per channel at 1Mbps with a 1.8V supply. The MAX14430/1/2 have an isolation rating of $3.75kV_{RMS}$ for 60 seconds. For applications requiring $5kV_{RMS}$ of isolation, see the MAX14434-MAX14436.

The MAX14430–MAX14432 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. Output enable for the A side of the MAX14431R/S/U/V is active-low, making them ideal for isolating a port on a shared SPI bus since the \overline{CS} signal can directly enable the MISO signal on the isolator. All other devices in the family have the traditional active-high enable.

Devices are available with a maximum data rate of either 25Mbps or 200Mbps and with outputs that are either default-high or default-low. The default is the state the output assumes when the input is either not powered or is open-circuit. See the <u>Ordering Information</u> for suffixes associated with each option. Independent 1.71V to 5.5V supplies on each side of the isolator also make the devices suitable for use as level translators.

The MAX14430–MAX14432 are available in a 16-pin narrow-body SOIC package with 4mm of creepage and clearance. The package material has a minimum comparative tracking index (CTI) of 600V, which gives it a group 1 rating in creepage tables. All devices are rated for operation at ambient temperatures of -40°C to +125°C.

Benefits and Features

- Robust Galvanic Isolation for Fast Digital Signals
 - Up to 200Mbps Data Rate
 - Withstands 3.75kV_{RMS} for 60s (V_{ISO})
 - Continuously Withstands 445V_{RMS} (V_{IOWM})
 - Withstands ±10kV Surge between GNDA and GNDB with 1.2/50µs waveform
 - High CMTI (50kV/µs, Typical)
- Low Power Consumption
 - 1.1mW per Channel at 1Mbps with V_{DD} = 3.3V
 - 3.5mW per Channel at 100Mbps with V_{DD} = 1.8V
- Options to Support a Broad Range of Applications
 2 Data Rates (25Mbps, 200Mbps)
 - 3 Channel Direction Configurations
 - 2 Output Default States (High/Low)

Applications

- Isolated SPI Interface
- Fieldbus Communications for Industrial Automation
- Isolated RS-485/RS-422, CAN
- Battery Management
- Medical Systems

Safety Regulatory Approvals

- UL According to UL1577
- cUL According to CSA Bulletin 5A

Ordering Information appears at end of data sheet.



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Absolute Maximum Ratings

V _{DDA} to GNDA	0.3V to +6V
V _{DDB} to GNDB	
IN_, EN_ on Side A to GNDA	0.3V to +6V
IN_, EN_ on Side B to GNDB	0.3V to +6V
OUT_ on Side A to GNDA	0.3V to (V _{DDA} + 0.3V)
OUT_ on Side B to GNDB	0.3V to (V _{DDB} + 0.3V)
Short-Circuit Duration	
OUT_ on Side A to GNDA,	
OUT_ on Side B to GNDB	Continuous

Continuous Power Dissipation	$(T_A = +70^{\circ}C)$
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0°C) 1066.7mW
40°C to +125°C
+150°C
60°C to +150°C
+260°C

Package Thermal Characteristics (Note 1)

Narrow SOIC

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

DC Electrical Characteristics

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15p\text{F}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 2)$

PARAMETER	SYMBOL	CON	CONDITIONS		TYP	MAX	UNITS
POWER SUPPLY	·	·					·
Supply Voltage	V _{DDA}	Relative to GNDA	Relative to GNDA			5.5	
Supply voltage	V _{DDB}	Relative to GNDB		1.71		5.5	v
Undervoltage-Lockout Threshold	V _{UVLO} _	V_{DD} rising		1.5	1.6	1.66	V
Undervoltage-Lockout Threshold Hysteresis	V _{UVLO_HYST}				45		mV
		500kHz square wave, C _L = 0pF	V _{DDA} = 5V		0.52	0.96	
			V _{DDA} = 3.3V		0.51	0.93	-
			V _{DDA} = 2.5V		0.50	0.92	
			V _{DDA} = 1.8V		0.49	0.64	
			V _{DDA} = 5V		1.63	2.42	
Supply Current (MAX14430_)		12.5MHz square	V _{DDA} = 3.3V		1.59	2.36	mA
(Note 3)	IDDA	wave, C _L = 0pF	V _{DDA} = 2.5V		1.58	2.33	
			V _{DDA} = 1.8V		1.54	2.00	
			V _{DDA} = 5V		4.5	6.14	
		50MHz square	V _{DDA} = 3.3V		4.39	6.00	
		wave, C _L = 0pF	V _{DDA} = 2.5V		4.35	5.93	
			V _{DDA} = 1.8V		4.21	5.43	

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DC Electrical Characteristics (continued)

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 2)$

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
			V _{DDB} = 5V		0.87	1.47	
		500kHz square wave, C _L = 0pF	V _{DDB} = 3.3V		0.82	1.41	_
			V _{DDB} = 2.5V		0.81	1.39	_
			V _{DDB} = 1.8V		0.79	1.32	
			V _{DDB} = 5V		2.97	3.84	
Supply Current (MAX14430_)		12.5MHz square	V _{DDB} = 3.3V		2.00	2.74]
(Note 3)	I _{DDB}	wave, $C_L = 0pF$	V _{DDB} = 2.5V		1.69	2.36	mA
			V _{DDB} = 1.8V		1.43	2.02]
			V _{DDB} = 5V		9.52	11.17	
		50MHz square	V _{DDB} = 3.3V		5.68	6.88	
		wave, $C_L = 0pF$	V _{DDB} = 2.5V		4.45	5.38]
			V _{DDB} = 1.8V		3.46	4.18	_
			V _{DDA} = 5V		0.62	1.10	
		500kHz square	V _{DDA} = 3.3V		0.60	1.06]
		wave, C _L = 0pF	V _{DDA} = 2.5V		0.59	1.05	- - - - - -
			V _{DDA} = 1.8V		0.57	0.83	
		12.5MHz square wave, C _L = 0pF	V _{DDA} = 5V		1.98	2.80	
	I _{DDA}		V _{DDA} = 3.3V		1.70	2.47	
			V _{DDA} = 2.5V		1.61	2.35	
			V _{DDA} = 1.8V		1.52	2.02	
			V _{DDA} = 5V		5.77	7.43	
		50MHz square	V _{DDA} = 3.3V		4.73	6.25	
		wave, C _L = 0pF	V _{DDA} = 2.5V		4.38	5.81	
Supply Current (MAX14431_)			V _{DDA} = 1.8V		4.03	5.15	
(Note 3)			V _{DDB} = 5V		0.78	1.35	
		500kHz square	V _{DDB} = 3.3V		0.75	1.30	
		wave, C _L = 0pF	V _{DDB} = 2.5V		0.74	1.28	
			V _{DDB} = 1.8V		0.72	1.16	
			V _{DDB} = 5V		2.64	3.49	
		12.5MHz square	V _{DDB} = 3.3V		1.90	2.65	
	I _{DDB}	wave, C _L = 0pF	V _{DDB} = 2.5V		1.66	2.36	- mA
			V _{DDB} = 1.8V		1.46	2.03	
			V _{DDB} = 5V		8.26	9.91	1
		50MHz square	V _{DDB} = 3.3V		5.36	6.66	-
		wave, C _L = 0pF	V _{DDB} = 2.5V		4.42	5.52	
			V _{DDB} = 1.8V		3.66	4.51	1

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DC Electrical Characteristics (continued)

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 2)$

PARAMETER	SYMBOL	CON	DITIONS	MIN	TYP	MAX	UNITS
			V _{DDA} = 5V		0.70	1.22	
		500kHz square	V _{DDA} = 3.3V		0.67	1.17	
		wave, C _L = 0pF	V _{DDA} = 2.5V		0.66	1.16	
			V _{DDA} = 1.8V		0.64	0.99	
			V _{DDA} = 5V		2.31	3.15	
		12.5MHz square	V _{DDA} = 3.3V		1.81	2.56	mA
	IDDA	wave, $C_L = 0pF$	V _{DDA} = 2.5V		1.64	2.35	
			V _{DDA} = 1.8V		1.50	2.02	
			V _{DDA} = 5V		7.04	8.70	
	1	50MHz square wave, C _L = 0pF	V _{DDA} = 3.3V		5.06	6.46	-
			V _{DDA} = 2.5V		4.40	5.67	
Supply Current (MAX14432_)			V _{DDA} = 1.8V		3.85	4.83	
(Note 3)		500kHz square	V _{DDB} = 5V		0.70	1.24	-
			V _{DDB} = 3.3V		0.67	1.19	
		wave, C _L = 0pF	V _{DDB} = 2.5V		0.66	1.17	
			V _{DDB} = 1.8V		0.65	1.00	
			V _{DDB} = 5V		2.31	3.15	
		12.5MHz square	V _{DDB} = 3.3V		1.80	2.57	mA
	IDDB	wave, C _L = 0pF	V _{DDB} = 2.5V		1.64	2.36	
			V _{DDB} = 1.8V		1.49	2.03	1
			V _{DDB} = 5V		7.01	8.66]
		50MHz square	V _{DDB} = 3.3V		5.04	6.46	
		wave, $C_L = 0pF$	V _{DDB} = 2.5V		4.40	5.67	
			V _{DDB} = 1.8V		3.84	4.83	

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DC Electrical Characteristics (continued)

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.}) (Note 2)$

PARAMETER	SYMBOL	CO	NDITIONS	MIN	TYP	MAX	UNITS
LOGIC INPUTS AND OUTPUTS		-					
Input High Voltage	Maria	EN_, IN_, relative to GND_	$2.25V \le V_{DD} \le 5.5V$	0.7 x V _{DD} _			v
Input High Voltage		EN_, IN_, relative to GND_	1.71V ≤ V _{DD} < 2.25V	0.75 x V _{DD} _			V
	Ma	EN_, IN_, relative to GND_	$2.25V \le V_{DD} \le 5.5V$			0.8	0.8
Input Low Voltage		EN_, IN_, relative to GND_	1.71V ≤ V _{DD} _ < 2.25V			0.7	
	V _{HYS}	EN_, IN_, relative to GND_	MAX1443_B/E/R/U		410		
Input Hysteresis		EN_, IN_, relative to GND_	MAX1443_C/F/S/V		80		mV
Input Pullup Current (Note 4)	I _{PU}	IN_, MAX1443_E	3/C/R/S	-10	-5	-1.5	μA
Input Pulldown Current (Note 4)	I _{PD}	IN_, MAX1443_E	E/F/U/V	1.5	5	10	μA
EN Pullup Current (Note 4)	I _{PU_EN}	EN_		-10	-5	-1.5	μA
Input Capacitance	C _{IN}	IN_, f _{SW} = 1MHz			2		pF
Output Voltage High (Note 4)	V _{OH}	V _{OUT} _relative to GND_ I _{OUT} _= -4mA source		V _{DD_} - 0.4			V
Output Voltage Low (Note 4)	V _{OL}	V _{OUT} _relative to I _{OUT} _= 4mA sink	GND_ <			0.4	V

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Dynamic Characteristics MAX1443_C/F/S/V

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 3)$

PARAMETER	SYMBOL		CONDITIONS	MIN	TYP	MAX	UNITS
Common-Mode Transient Immunity	СМТІ	IN_ = GND_	or V _{DD_} (Note 5)		50		kV/µs
Maximum Data Rate	DB	2.25V ≤ V _{DD}	$2.25V \le V_{DD} \le 5.5V$				Mbps
	DR _{MAX}	1.71V ≤ V _{DD}	_≤ 2.24V	150			winthe
Minimum Pulse Width	PW _{MIN}	IN_ to	$2.25V \le V_{DD} \le 5.5V$			5	ns
		OUT_	$1.71V \le V_{DD} \le 1.89V$			6.67	
Propagation Delay (Figure 1)			$4.5V \le V_{DD} \le 5.5V$	4.1	5.4	9.2	_
	IN_to t _{PLH} OUT_,	$3.0V \le V_{DD} \le 3.6V$	4.2	5.9	10.2		
	^t PLH	C _L = 15pF	$2.25 \text{V} \leq \text{V}_{\text{DD}} \leq 2.75 \text{V}$	4.9	7.1	13.4	
		1.71V ≤ V _{DD} _ ≤ 1.89V	7.1	10.9	20.3	ns	
		IN_to t _{PHL} OUT_, C _L = 15pF	$4.5V \le V_{DD} \le 5.5V$	4.3	5.6	9.4	
			$3.0V \le V_{DD} \le 3.6V$	4.4	6.2	10.5	
	PHL		2.25V ≤ V _{DD} _ ≤ 2.75V	5.1	7.3	14.1	
			1.71V ≤ V _{DD} _ ≤ 1.89V	7.2	10.9	21.7	
Pulse Width Distortion	PWD	t _{PLH} - t _{PHL}			0.3	2	ns
		4.5V ≤ V _{DD} _	≤ 5.5V			3.7	
	tapuu	3.0V ≤ V _{DD} _	≤ 3.6V			4.3	
	^t SPLH	2.25V ≤ V _{DD}	_≤2.75V			6	
Propagation Delay Skew		1.71V ≤ V _{DD}	_≤ 1.89V			10.3	ns
Part-to-Part (Same Channel)		4.5V ≤ V _{DD} _	≤ 5.5V			3.8	- ns
		3.0V ≤ V _{DD} _	≤ 3.6V			4.7	
	tSPHL	2.25V ≤ V _{DD}	 2.25V ≤ V _{DD} _ ≤ 2.75V			6.5	
		1.71V ≤ V _{DD}	_≤ 1.89V			11.5	
Propagation Delay Skew	t _{SCSLH}	1.71V ≤ V _{DD}	1.71V ≤ V _{DD} _ ≤ 5.5V			1.5	
Channel-to-Channel (Same Direction)	t _{SCSHL}	1.71V ≤ V _{DD}	≤ 5.5V			1.5	ns

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Dynamic Characteristics MAX1443_C/F/S/V (continued)

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 3)$

PARAMETER	SYMBOL	(CONDITIONS	MIN	ТҮР	MAX	UNITS
		4.5V ≤ V _{DD} _	≤ 5.5V			2.9	
		3.0V ≤ V _{DD} _	$3.0V \le V_{DD} \le 3.6V$			3.4	
	^t SCOLH	2.25V ≤ V _{DD}	_≤2.75V			4.9	
Propagation Delay Skew Channel-to-Channel		1.71V ≤ V _{DD}	_≤ 1.89V			10.2	
(Opposite Direction)		4.5V ≤ V _{DD} _	≤ 5.5V			3.2	ns
		3.0V ≤ V _{DD} _	≤ 3.6V			3.8	
	^t SCOHL	2.25V ≤ V _{DD}	_≤2.75V			5.3	
		1.71V ≤ V _{DD}	_≤ 1.89V			10.9	
Peak Eye Diagram Jitter	T _{JIT(PK)}	200Mbps			90		ps
Clock Jitter RMS	T _{JCLK(RMS)}	500kHz Clock	Input, Rising/Falling Edges		6.5		ps
		$4.5V \le V_{\text{DD}} \le 5.5V$				1.6	
Rise Time	+_	$3.0V \le V_{DD} \le 3.6V$				2.2 ns	
Rise Time	t _R	$2.25V \le V_{DD} \le 2.75V$					115
		$1.71V \le V_{DD} \le 1.89V$				4.5	5
		$4.5V \le V_{DD}$	≤ 5.5V			1.4	
Fall Time	+ _	$3.0V \le V_{DD} \le 3.6V$				2	
	t _F	2.25V ≤ V _{DD} ≤ 2.75V				2.8	ns
		1.71V ≤ V _{DD}	_≤1.89V			5.1	
		ENA to	$4.5V \le V_{DD} \le 5.5V$			3.5	
Enable to Data Valid	t	OUT_, ENB to	$3.0V \le V_{DD} \le 3.6V$			5.8	ne
	^t EN	OUT_,	$2.25V \le V_{DD} \le 2.75V$			9.3	ns
		C _L = 15pF	$1.71V \le V_{DD} \le 1.89V$			17.4	
		ENA to	$4.5V \le V_{DD} \le 5.5V$			6.4	
Enable to Tristate	t==.	OUT_,	$3.0V \le V_{DD} \le 3.6V$			9.2	- ns
	t _{TRI}	ENB to OUT_,	$2.25V \le V_{DD} \le 2.75V$			12.8	
		C _L = 15pF	$1.71V \le V_{DD} \le 1.89V$			19.4	

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Dynamic Characteristics MAX1443_B/E/R/U

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15\text{pF}, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted}. Typical values are at V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted}.) (Note 3)$

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Common-Mode Transient Immunity	СМТІ	IN_ = GND_	or V _{DD_} (Note 5)		50		kV/µs	
Maximum Data Rate	DR _{MAX}						Mbps	
Minimum Pulse Width	PWMIN	IN_ to OUT_				40	ns	
Glitch Rejection		IN_ to OUT_		10	17	29	ns	
			$4.5V \le V_{DD} \le 5.5V$	17.4	23.9	32.5		
	t	IN_to OUT_,	$3.0V \le V_{DD} \le 3.6V$	17.6	24.4	33.7		
	t _{PLH}	$C_{I} = 15 pF$	$2.25V \le V_{DD} \le 2.75V$	18.3	25.8	36.7		
Propagation Delay			1.71V ≤ V _{DD} _ ≤ 1.89V	20.7	29.6	43.5	ns	
(Figure 1)	t _{PHL} IN_ to C _L = 15pF	$4.5V \le V_{DD} \le 5.5V$	16.9	23.4	33.6	115		
		$3.0V \le V_{DD} \le 3.6V$	17.2	24.2	35.1			
			$2.25V \le V_{DD} \le 2.75V$	17.8	25.4	38.2		
			1.71V ≤ V _{DD} _ ≤ 1.89V	19.8	29.3	45.8		
Pulse Width Distortion	PWD	t _{PLH} -t _{PHL}			0.4	4	ns	
		4.5V ≤ V _{DD} _	$4.5V \le V_{DD} \le 5.5V$			15.1		
	t _{SPLH}	3.0V ≤ V _{DD} _	≤ 3.6V			15		
		2.25V ≤ V _{DD}	$2.25V \le V_{DD} \le 2.75V$			15.4	-	
Propagation Delay Skew		1.71V ≤ V _{DD} ≤ 1.89V				20.5	ns	
Part-to-Part (Same Channel)		$4.5V \le V_{DD} \le 5.5V$				13.9	113	
	t _{SPHL}	$3.0V \le V_{DD} \le 3.6V$				14.2		
	SPAL	2.25V ≤ V _{DD}	_≤2.75V			16		
		1.71V ≤ V _{DD}	_≤ 1.89V			21.8		
Propagation Delay Skew Channel-to-Channel	t _{SCSLH}	1.71V ≤ V _{DD}	_≤ 5.5V			2		
(Same Direction)	tSCSHL	1.71V ≤ V _{DD}	_≤ 5.5V			2	ns	
		4.5V ≤ V _{DD} _	≤ 5.5V			13.9		
		3.0V ≤ V _{DD}	≤ 3.6V			13.7	1	
Propagation Delay Skew	tSCOLH	2.25V ≤ V _{DD}	_≤2.75V			14.2]	
		1.71V ≤ V _{DD}				19.4		
Channel-to-Channel (Opposite Direction)		4.5V ≤ V _{DD} _	≤ 5.5V			13	ns	
,		3.0V ≤ V _{DD}	≤ 3.6V			12.9	1	
	t _{SCOHL} 2.25V ≤ V		_≤2.75V			14.4	1	
		1.71V ≤ V _{DD}	1V ≤ V _{DD} ≤ 1.89V			20.1	1	

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Dynamic Characteristics MAX1443_B/E/R/U (continued)

 $(V_{DDA} - V_{GNDA} = 1.71V \text{ to } 5.5V, V_{DDB} - V_{GNDB} = 1.71V \text{ to } 5.5V, C_L = 15pF, T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted. Typical values are at } V_{DDA} - V_{GNDA} = 3.3V, V_{DDB} - V_{GNDB} = 3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C, \text{ unless otherwise noted.}$ (Note 3)

PARAMETER	SYMBOL		CONDITIONS		TYP	MAX	UNITS	
Peak Eye Diagram Jitter	T _{JIT(PK)}	25Mbps			250		ps	
		4.5V ≤ V _{DD} _	≤ 5.5V			1.6		
Diag Time (Figure 1)		3.0V ≤ V _{DD} _	≤ 3.6V			2.2		
Rise Time (Figure 1)	t _R	2.25V ≤ V _{DD}	≤ 2.75V			3	ns	
		1.71V ≤ V _{DD}	_≤ 1.89V			4.5	1	
		4.5V ≤ V _{DD} _	≤ 5.5V			1.4		
		3.0V ≤ V _{DD} _	$\frac{-}{3.0V \le V_{DD}} \le 3.6V$			2]	
Fall Time (Figure 1)	t _F	2.25V ≤ V _{DD} _ ≤ 2.75V				2.8	ns	
		1.71V ≤ V _{DD}	≤ 1.89V			5.1]	
		ENA to	$4.5V \le V_{DD} \le 5.5V$			3.5		
Enable to Data Valid		OUT_,	$3.0V \le V_{DD} \le 3.6V$			5.8		
	^t EN	ENB to OUT_,	$2.25V \le V_{DD} \le 2.75V$			9.3	ns	
		C _L = 15pF	$1.71V \le V_{DD} \le 1.89V$			17.4	1	
	ENA t		ENA to	$4.5V \le V_{DD} \le 5.5V$			6.4	
Enable to Tristate t-	•	OUT_,	$3.0V \le V_{DD} \le 3.6V$			9.2		
	t _{TRI}	ENB to OUT_,	2.25V ≤ V _{DD} _ ≤ 2.75V			12.8	ns	
		C _L = 15pF	1.71V ≤ V _{DD} _ ≤ 1.89V			19.4		

Note 2: All devices are 100% production tested at $T_A = +25$ °C. Specifications over temperature are guaranteed by design and characterization.

Note 3: Not production tested. Guaranteed by design and characterization.

Note 4: All currents into the device are positive. All currents out of the device are negative. All voltages are referenced to their respective ground (GNDA or GNDB), unless otherwise noted.

Note 5: CMTI is the maximum sustainable common-mode voltage slew rate while maintaining the correct output. CMTI applies to both rising and falling common-mode voltage edges. Tested with the transient generator connected between GNDA and GNDB (V_{CM} = 1000V).

ESD Protection

PARAMETER	SYMBOL	CONDITIONS		TYP	MAX	UNITS
ESD		Human Body Model, All Pins		±4		kV

Safety Regulatory Apporvals

UL
The MAX14430–MAX14432 are certified under UL 1577. For more details, refer to file E351759.
Rated up to 3750V _{RMS} isolation voltage for single protection.
cUL (Equivalent to CSA notice 5A)
The MAX14430–MAX14432 are certified up to 3750V _{RMS} for single protection. For more details, refer to file E351759.

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Table 1. Narrow SOIC Insulation Characteristics

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNITS	
Partial Discharge Test Voltage	V _{PR}	Method B1 = V _{IORM} x 1.875 (t = 1s, partial discharge < 5pC)	1182	V _P	
Maximum Repetitive Peak Isolation Voltage	V _{IORM}	(Note 6)	630	VP	
Maximum Working Isolation Voltage	V _{IOWM}	Continuous RMS voltage (Note 6)	445	V _{RMS}	
Maximum Transient Isolation Voltage	V _{IOTM}	t = 1s	6000	V _P	
Maximum Withstand Isolation Voltage	V _{ISO}	f _{SW} = 60Hz, duration = 60s (Note 7)	3750	V _{RMS}	
Maximum Surge Isolation Voltage	V _{IOSM}	Basic Insulation, 1.2/50µs pulse per IEC61000-4-5	10	kV	
		V _{IO} = 500V, T _A = 25°C	>10 ¹²		
Insulation Resistance	R _{IO}	$V_{IO} = 500V, 100^{\circ}C \le T_A \le 125^{\circ}C$	>10 ¹¹		
		V _{IO} = 500V at T _A = 150°C	>10 ⁹		
Barrier Capacitance Side A to Side B	CIO	f _{SW} = 1MHz (Note 8)	2	pF	
Minimum Creepage Distance	CPG	Narrow SOIC	4	mm	
Minimum Clearance Distance	CLR	Narrow SOIC	4	mm	
Internal Clearance		Distance through insulation	0.015	mm	
Comparative Tracking Index	СТІ	Material Group I (IEC 60112)	>600		
Climate Category			40/125/21		
Pollution Degree (DIN VDE 0110, Table 1)			2		

Note 6: V_{ISO}, V_{IOWM}, and V_{IORM} are defined by the IEC 60747-5-5 standard.

Note 7: Product is qualified at V_{ISO} for 60s and 100% production tested at 120% of V_{ISO} for 1s.

Note 8: Capacitance is measured with all pins on field-side and logic-side tied together.

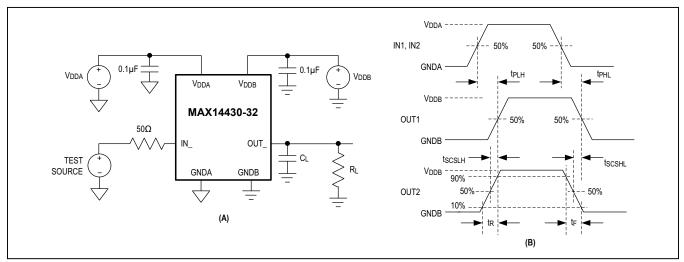
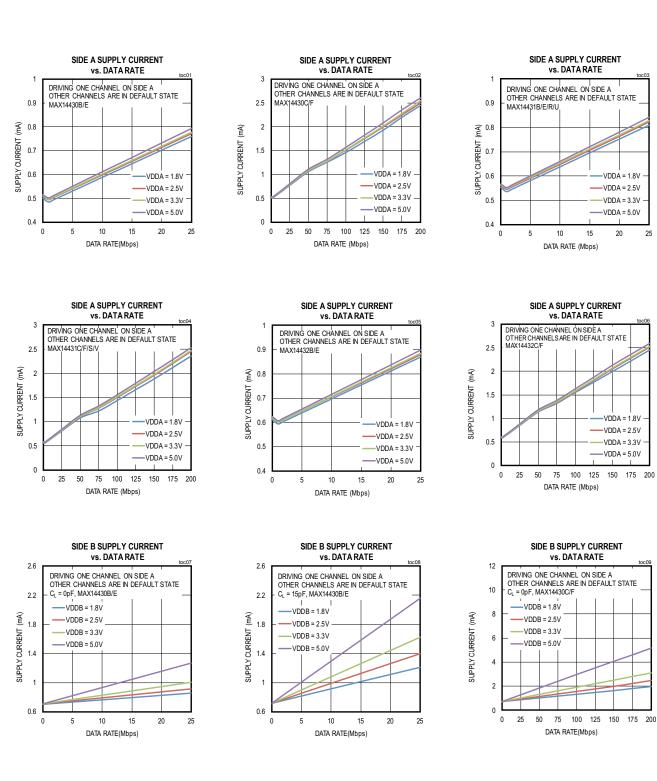


Figure 1. Test Circuit (A) and Timing Diagram (B)

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Typical Operating Characteristics

(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.)

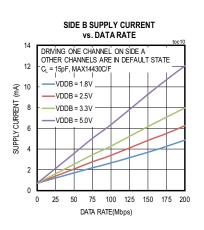


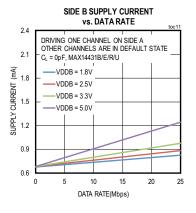
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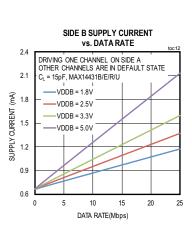
Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

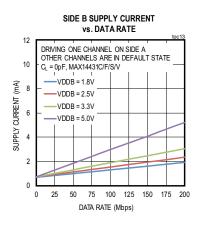
Typical Operating Characteristics (continued)

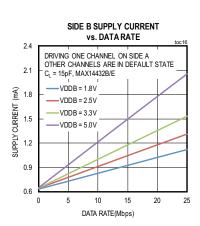
(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25°C, unless otherwise noted.)

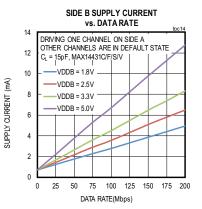


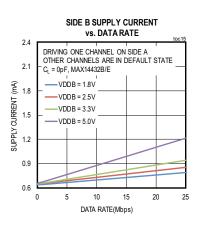


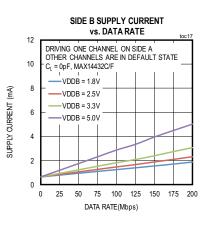




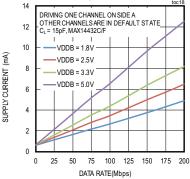








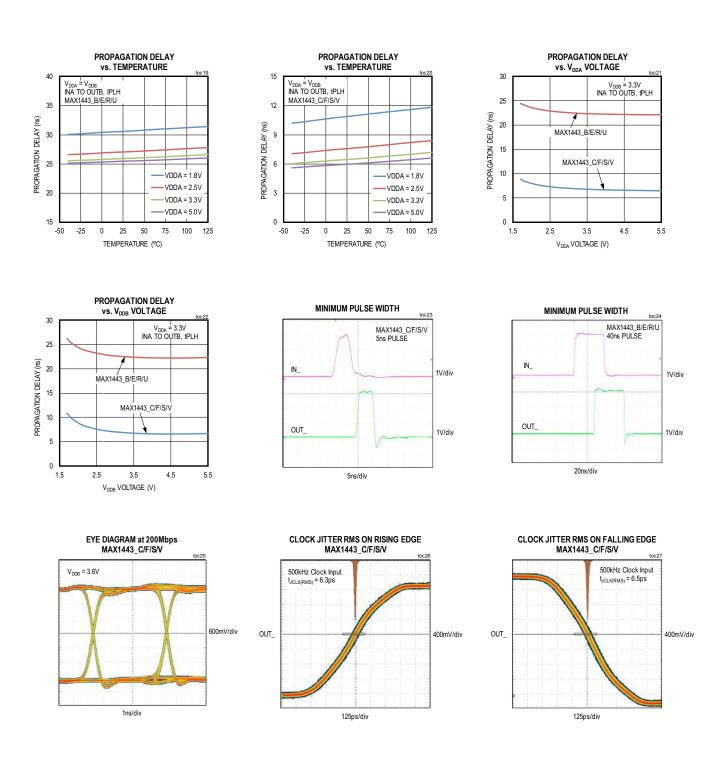




Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

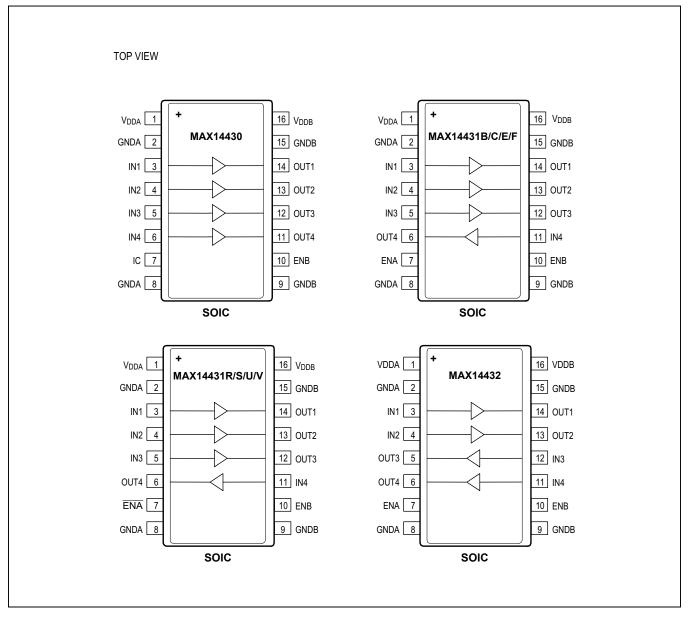
Typical Operating Characteristics (continued)

 $(V_{DDA} - V_{GNDA} = +3.3V, V_{DDB} - V_{GNDB} = +3.3V, V_{GNDA} = V_{GNDB}, T_A = +25^{\circ}C$, unless otherwise noted.)



Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Pin Configurations

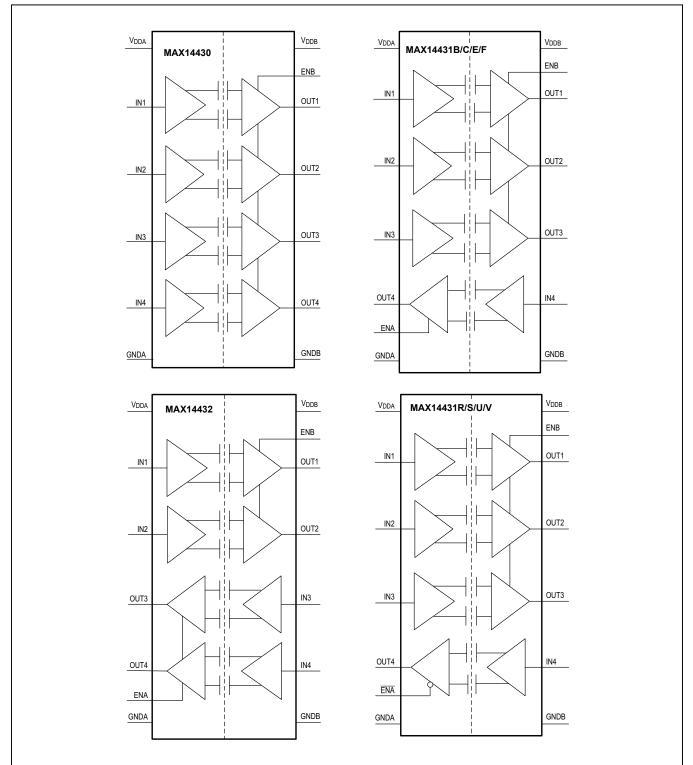


Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Pin Description

NAME	PIN			EUNCTION	
NAME	MAX14430	MAX14431B/C/E/F	MAX14431R/S/U/V	MAX14432	FUNCTION
V _{DDA}	1	1	1	1	Power Supply. Bypass V_{DDA} with a 0.1µF ceramic capacitor as close as possible to the pin.
GNDA	2, 8	2, 8	2, 8	2, 8	Ground Reference for Side A
IN1	3	3	3	3	Logic Input 1 on Side A. Corresponds to Logic Output 1 on Side B
IN2	4	4	4	4	Logic Input 2 on Side A. Corresponds to Logic Output 2 on Side B
IN3	5	5	5	12	Logic Input 3 on Side A or B. Corresponds to Logic Output 3 on Side B or A
IN4	6	11	11	11	Logic Input 4 on Side A or B. Corresponds to Logic Output 4 on Side B or A
I.C.	7	_	_	—	Internally Connected. Leave unconnected or connect to GNDA or V _{DDA} .
ENA	—	7	_	7	Active-High Enable for Side A. ENA has an internal 5µA pullup to V _{DDA} .
ENA	—	_	7	—	Active-Low Enable for Side A. $\overline{\text{ENA}}$ has an internal 5µA pullup to V_{DDA}
OUT1	14	14	14	14	Logic Output 1 on Side B
OUT2	13	13	13	13	Logic Output 2 on Side B
OUT3	12	12	12	5	Logic Output 3 on Side A or Side B
OUT4	11	6	6	6	Logic Output 4 on Side A or Side B
ENB	10	10	10	10	Active-High Enable for Side B. ENB has an internal 5μ A pullup to V _{DDB} .
GNDB	9, 15	9, 15	9, 15	9, 15	Ground Reference for Side B
V _{DDB}	16	16	16	16	Power Supply. Bypass V_{DDB} with a 0.1µF ceramic capacitor as close as possible to the pin.

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators



Functional Diagram

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Detailed Description

The MAX14430–MAX14432 is a family of 4-channel digital isolators. The MAX14430–MAX14432 have an isolation rating of $3.75kV_{RMS}$. The MAX14430–MAX14432 family offers all three possible unidirectional channel configurations to accommodate any 4-channel design, including SPI, RS-232, RS-485, and digital I/O applications. For applications requiring bidirectional channels, such as I²C, see the MAX14933 and MAX14937.

The MAX14430 features four channels transferring digital signals in one direction for applications such as isolated digital I/O. The MAX14431 has three channels transmitting data in one direction and one channel transmitting in the opposite direction, making it ideal for applications such as isolated SPI and RS-485 communication. The MAX14432 provides further design flexibility with two channels in each direction for isolated RS-232 or other applications.

Devices are available in the 16-pin narrow-body SOIC package and are rated for up to $3.75 kV_{RMS}$. This family of digital isolators offers low-power operation, high electromagnetic interference (EMI) immunity, and stable temperature performance through Maxim's proprietary process technology. The devices isolate different ground domains and block high-voltage/high-current transients from sensitive or human interface circuitry.

Devices are available with a maximum data rate of either 25Mbps (B/E/R/U versions) or 200Mbps (C/F/S/V versions). Each device can be ordered with default-high or default-low outputs. The default is the state the output assumes when the input is not powered or if the input is open circuit. The devices have two supply inputs (V_{DDA} and V_{DDB}) that independently set the logic levels on either side of the device. V_{DDA} and V_{DDB} are referenced to GNDA and GNDB, respectively. The MAX14430–MAX14432 family also features a refresh circuit to ensure output accuracy when an input remains in the same state indefinitely.

Digital Isolation

The MAX14430–MAX14432 family provides galvanic isolation for digital signals that are transmitted between two ground domains. The devices withstand differences of up to $3.75 kV_{RMS}$ for up to 60 seconds, and up to $630V_{PEAK}$ of continuous isolation.

Level-Shifting

The wide supply voltage range of both V_{DDA} and V_{DDB} allows the MAX14430–MAX14432 family to be used for level translation in addition to isolation. V_{DDA} and V_{DDB} can be independently set to any voltage from 1.71V to 5.5V. The supply voltage sets the logic level on the corresponding side of the isolator.

Unidirectional Channels

Each channel of the MAX14430–MAX14432 is unidirectional; it only passes data in one direction, as indicated in the functional diagram. Each device features four unidirectional channels that operate independently with guaranteed data rates from DC up to 25Mbps (B/E/R/U versions), or from DC to 200Mbps (C/F/S/V versions). The output driver of each channel is push-pull, eliminating the need for pullup resistors. The outputs are able to drive both TTL and CMOS logic inputs.

Startup and Undervoltage-Lockout

The V_{DDA} and V_{DDB} supplies are both internally monitored for undervoltage conditions. Undervoltage events can occur during power-up, power-down, or during normal operation due to a sagging supply voltage. When an undervoltage condition is detected on either supply while the outputs are enabled, all outputs go to their default states regardless of the state of the inputs (<u>Table 2</u>). Figure 2 through Figure 5 show the behavior of the outputs during power-up and power-down.

V _{IN_}	V _{DDA}	V _{DDB}	ENA	ENB	V _{OUTA}	V _{OUTB}
1	Doworod	Doworod	1	1	1	1
1	Powered	Powered	0	0	Hi-Z	Hi-Z
0	0 Powered	Powered	1	1	0	0
0			0	0	Hi-Z	Hi-Z
×		Powered	1	1	Default	Default
X	Undervoltage		0	0	Hi-Z	Hi-Z
x	Deverad		1	1	Default	Default
×	Powered	Undervoltage	0	0	Hi-Z	Hi-Z

Table 2. MAX1443_B/C/E/F Output Behavior During Undervoltage Conditions

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Table 3. MAX14431R/S/U/V Output Behavior During Undervoltage Conditions

V _{IN} _	V _{DDA}	V _{DDB}	ENA	ENB	V _{OUTA}	V _{OUTB}
4	Deverad	Dewered	0	1	1	1
I	Powered	Powered	1	0	Hi-Z	Hi-Z
0	0 Powered	Powered Powered	0	1	0	0
U			1	0	Hi-Z	Hi-Z
×		dervoltage Powered	0	1	Default	Default
X	Undervoltage		1	0	Hi-Z	Hi-Z
×	Devuered	Undervoltage	0	1	Default	Default
X	Powered		1	0	Hi-Z	Hi-Z

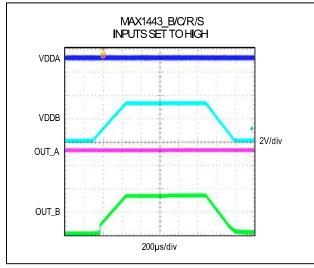


Figure 2. Undervoltage Lockout Behavior (MAX1443_B/C/R/S High)

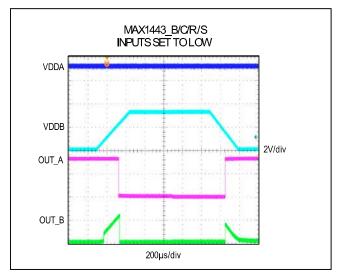


Figure 4. Undervoltage Lockout Behavior (MAX1443_B/C/R/S Low)

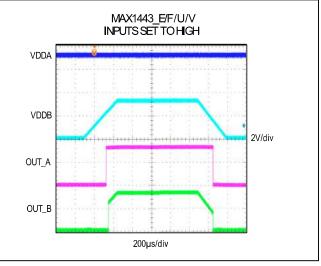


Figure 3. Undervoltage Lockout Behavior (MAX1443_E/F/U/V High)

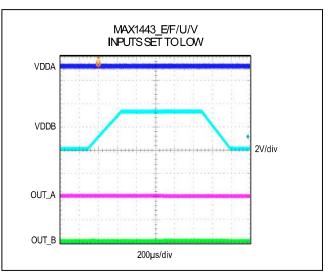


Figure 5. Undervoltage Lockout Behavior (MAX1443_E/F/U/V Low)

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Applications Information

Power-Supply Sequencing

The MAX14430–MAX14432 do not require special power supply sequencing. The logic levels are set independently on either side by V_{DDA} and V_{DDB} . Each supply can be present over the entire specified range regardless of the level or presence of the other supply.

Power-Supply Decoupling

To reduce ripple and the chance of introducing data errors, bypass V_{DDA} and V_{DDB} with 0.1µF low-ESR ceramic capacitors to GNDA and GNDB, respectively. Place the bypass capacitors as close to the power supply input pins as possible.

Layout Considerations

The PCB designer should follow some critical recommendations in order to get the best performance from the design.

- Keep the input/output traces as short as possible. Avoid using vias to make low-inductance paths for the signals.
- Have a solid ground plane underneath the highspeed signal layer.
- Keep the area underneath the MAX14430–MAX14432 free from ground and signal planes. Any galvanic or metallic connection between the field-side and logic-side defeats the isolation.

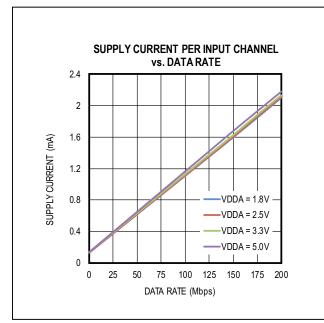


Figure 6. Supply Current Per Input Channel (Estimated)

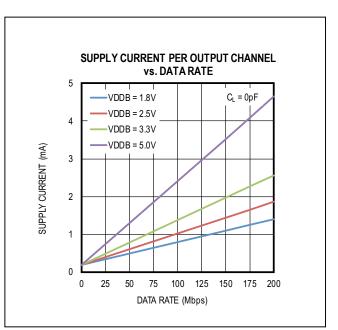


Figure 7. Supply Current Per Output Channel (Estimated)

Calculating Power Dissipation

The required current for a given supply (V_{DDA} or V_{DDB}) can be estimated by summing the current required for each channel. The supply current for a channel depends on whether the channel is an input or an output, the channel's data rate, and the capacitive or resistive load if it is an output. The typical current for an input or output at any data rate can be estimated from the graphs in Figure 6 and Figure 7. Please note the data in Figure 6 and Figure 7 are extrapolated from the supply current measurements in a typical operating condition.

The total current for a single channel is the sum of the "no load" current (shown in Figure 6 and Figure 7) which is a function of Voltage and Data Rate, and the "load current," which depends on the type of load. Current into a capacitive load is a function of the load capacitance, the switching frequency, and the supply voltage.

$$I_{CL} = C_L \times f_{SW} \times V_{DD}$$

where

 I_{CI} is the current required to drive the capacitive load.

C_I is the load capacitance on the isolator's output pin.

 f_{SW} is the switching frequency (bits per second/2).

V_{DD} is the supply voltage on the output side of the isolator.

Current into a resistive load depends on the load resistance, the supply voltage and the average duty cycle of the data waveform. The DC load current can be conservatively estimated by assuming the output is always high.

$$I_{RL} = V_{DD} \div R_L$$

where

 I_{RL} is the current required to drive the resistive load.

 V_{DD} is the supply voltage on the output side of the isolator. R_L is the load resistance on the isolator's output pin.

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Example (shown in Figure 8): A MAX14431F is operating with V_{DDA} = 2.5V, V_{DDB} = 3.3V, channel 1 operating at 20Mbps with a 10pF capacitive load, channel 2 held high with a 10k Ω resistive load, and channel 4 operating at 100Mbps with a 15pF capacitive load. Channel 3 is not in use and the resistive load is negligible since the isolator is driving a CMOS input. Refer to <u>Table 4</u> and <u>Table 5</u> for V_{DDA} and V_{DDB} supply current calculation worksheets.

V_{DDA} must supply:

- Channel 1 is an input channel operating at 2.5V and 20Mbps, consuming 0.33mA, estimated from Figure 6.
- Channel 2 and 3 are input channels operating at 2.5V with DC signal, consuming 0.13mA, estimated from Figure 6.
- Channel 4 is an output channel operating at 2.5V and 100Mbps, consuming 1.02mA, estimated from Figure 7.
- I_{CL} on channel 4 for 15pF capacitor at 2.5V and 100Mbps is 1.875mA.

Total current for side A = 0.33 + 0.13 × 2 + 1.02 + 1.875 = 3.485mA, typical

V_{DDB} must supply:

- Channel 1 is an output channel operating at 3.3V and 20Mbps, consuming 0.42mA, estimated from Figure 7.
- Channel 2 and 3 are output channels operating at 3.3V with DC signal, consuming 0.18mA, estimated from Figure 7.
- Channel 4 is an input channel operating at 3.3V and 100Mbps, consuming 1.13mA, estimated from Figure 6.
- I_{CL} on channel 1 for 10pF capacitor at 3.3V and 20Mbps is 0.33mA.
- I_{RL} on channel 2 for 10kΩ resistor held at 3.3V is 0.33mA.

Total current for side B = 0.42 + 0.18 × 2 + 1.13 + 0.33 + 0.33 = 2.57mA, typical

Table 4. Side A Supply Current Calculation Worksheet

SIDE A		V _{DDA} = 2.5V							
Channel	IN/ OUT	Data Rate (Mbps)	Load Type	Load	"No Load" Current (mA)	Load Current (mA)			
1	IN	20			0.33				
2	IN	0			0.13				
3	IN	0			0.13				
4	OUT	100	Capacitive	15pF	1.02	2.5V x 50MHz x 15pF = 1.875mA			
Total: 3.485mA									

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

table of olde B oupply our out outcallation from shoet										
SIDE B		V _{DDB} = 3.3V								
Channel	IN/ OUT	Data Rate (Mbps)	Load Type	Load	"No Load" Current (mA)	Load Current (mA)				
1	OUT	20	Capacitive	10pF	0.42	3.3V x 10MHz x 10pF = 0.33mA				
2	OUT	0	Resistive	10kΩ	0.18	3.3V / 10kΩ = 0.33mA				
3	OUT	0			0.18					
4	IN	100			1.13					
	Total: 2.57mA									

Table 5. Side B Supply Current Calculation Worksheet

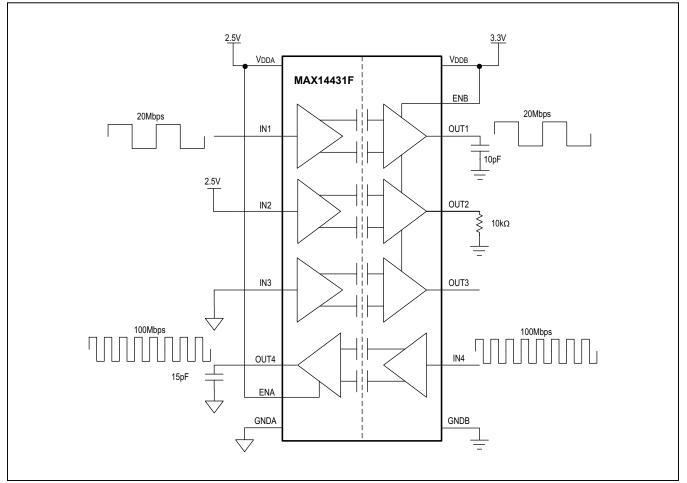
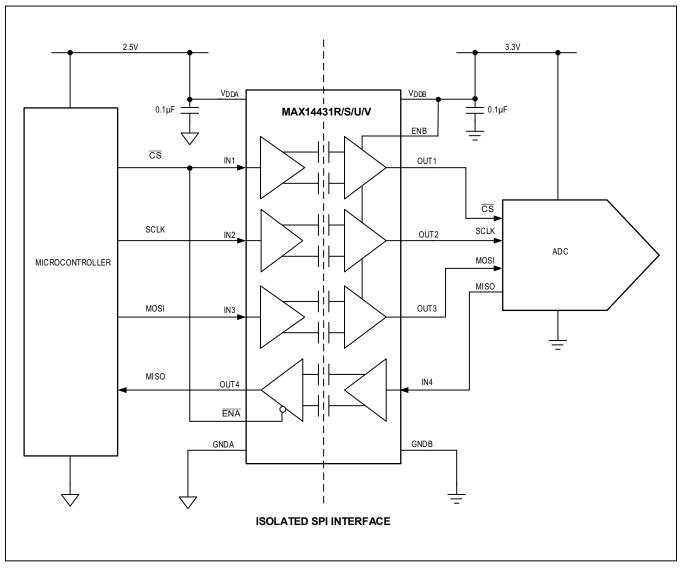


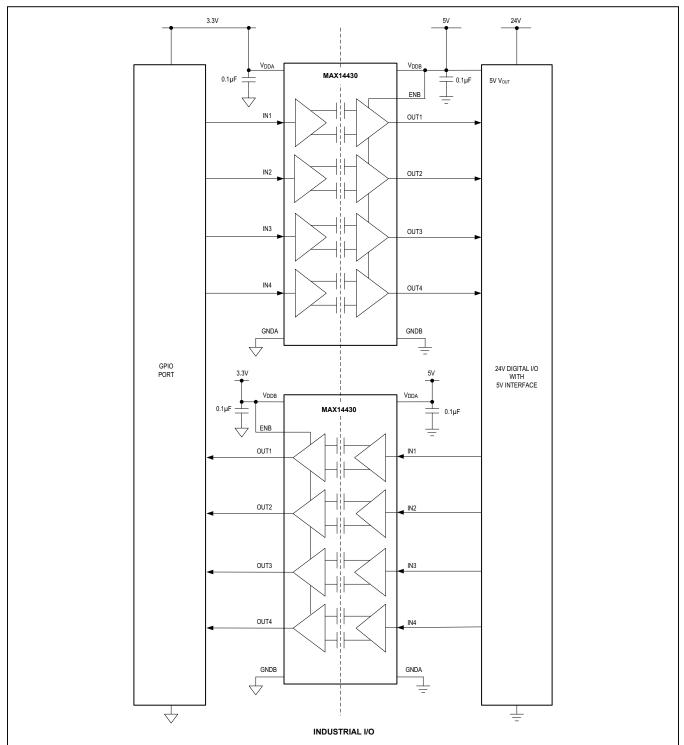
Figure 8. Example Circuit for Supply Current Calculation

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Typical Operating Circuit

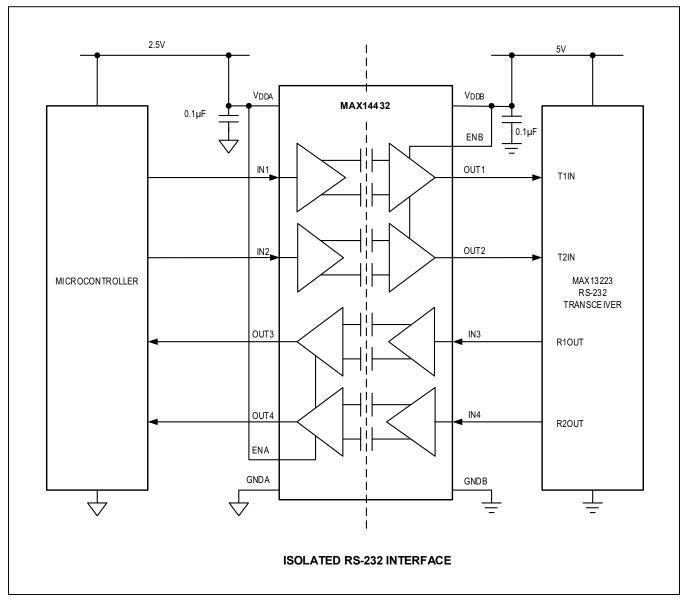


Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators



Typical Operating Circuit (continued)

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators



Typical Operating Circuit (continued)

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Ordering Information

PART	CHANNEL CONFIGU- RATION	DATA RATE (Mbps)	DEFAULT OUTPUT	ENA Polarity	ISOLATION VOLTAGE (kV _{RMS})	TEMP RANGE (°C)	PIN-PACKAGE
MAX14430BASE+*	4/0	25	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14430CASE+*	4/0	200	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14430EASE+*	4/0	25	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14430FASE+*	4/0	200	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14431BASE+*	3/1	25	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14431CASE+*	3/1	200	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14431EASE+*	3/1	25	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14431FASE+*	3/1	200	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14431RASE+*	3/1	25	Default High	Active-Low	3.75	-40 to +125	16 Narrow SOIC
MAX14431SASE+*	3/1	200	Default High	Active-Low	3.75	-40 to +125	16 Narrow SOIC
MAX14431UASE+*	3/1	25	Default Low	Active-Low	3.75	-40 to +125	16 Narrow SOIC
MAX14431VASE+*	3/1	200	Default Low	Active-Low	3.75	-40 to +125	16 Narrow SOIC
MAX14432BASE+*	2/2	25	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14432CASE+*	2/2	200	Default High	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14432EASE+*	2/2	25	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC
MAX14432FASE+	2/2	200	Default Low	Active-High	3.75	-40 to +125	16 Narrow SOIC

*Future Product—Contact Maxim for availability.

+Denotes a lead(Pb)-free/RoHS-compliant package.

Package Information

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
16 Narrow SOIC	S16MS+12	<u>21-0041</u>	<u>90-0442</u>

Chip Information

PROCESS: BICMOS

Four-Channel, Fast, Low-Power, 3.75kV_{RMS} Digital Isolators

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	11/17	Initial release	—
1	11/17	Updated Benefits and Features section, Electrical Characteristics table, Typical Operating Characteristics section, Table 3, and Typical Operating Circuit	1, 5, 6, 9, 11, 12,

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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